RICOH

RP130x Series

Low Noise 150 mA LDO Regulator

No. EA-173-180607

OUTLINE

The RP130x is a voltage regulator IC with high ripple rejection, low dropout voltage, high output voltage accuracy and extremely low supply current. The IC consists of a voltage reference unit, an error amplifier, a resistor-net for voltage setting, a short current limit circuit and a chip enable circuit.

This IC has an excellent low supply current performed by CMOS process, moreover they perform with low dropout voltage due to built-in low on-resistance. A chip enable function prolongs the battery life.

The input transient response, the load transient response and the ripple rejection have been improved in the RP130x compared with the conventional products. Besides achieving low supply current (Typ.38 µA).

The range of the operation voltage is capable from 1.7 V to 6.5 V and the range of the output voltage is capable from 1.2 V to 5.3 V for this product, which is wider range as our conventional product R1114x.

The output voltage of this IC is fixed with high accuracy. Since the packages for this IC are DFN(PLP)1010-4, SOT-23-5 and SC-82AB, therefore high density mounting of the IC on board is possible.

FEATURES

Supply Current	Τyp. 38 μA
Standby Current	Τyp. 0.1 μA
Ripple Rejection	Typ. 80 dB (f = 1 kHz)
Input Voltage Range (Maximum Rating)	1.7 V to 6.5 V (7.0 V)
Output Voltage Range	1.2 V to 5.3 V (0.1 V step ⁽¹⁾)
Output Voltage Accuracy	±1.0% (Vо∪т > 2.0 V, Ta = 25°C)
• Temperature-Drift Coefficient of Output Voltage	Typ. ±20 ppm/°C
Dropout Voltage	Typ. 0.32 V (Iout = 150 mA, Vout = 2.8 V)
Line Regulation	Typ. 0.02%/V
Packages	DFN(PLP)1010-4, SC-82AB, SOT-23-5
Built-in Fold Back Protection Circuit	Typ. 40 mA
Ceramic capacitors are recommended to be used	d with this IC0.47 μF or more

APPLICATIONS

- Power source for battery-powered equipment.
- Power source for portable communication equipment.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- Power source for high stable reference voltage.

⁽¹⁾ For other voltages, please refer to SELECTION GUIDE.

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SELECTION GUIDE

The set output voltage, chip enable polarity, auto-discharge function⁽¹⁾, and packages for the IC can be selected at the user's request.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free	
RP130Kxx1*-TR	DFN(PLP)1010-4	10,000 pcs	Yes	Yes	
RP130Qxx1*-TR-FE	SC-82AB	3,000 pcs	Yes	Yes	
RP130Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes	

xx: Set Output Voltage (VSET)

Fixed Type: 12 to 53 Stepwise setting with 0.1 V increment in the range from 1.2 V to 5.3 V

Exception: 1.25 V = RP130x121*5

1.85 V = RP130x181*5

2.85 V = RP130x281*5

3.45 V = RP130x341*5

4.25 V = RP130x421*5

* : CE pin polarity and auto-discharge function at off state are options as follows.

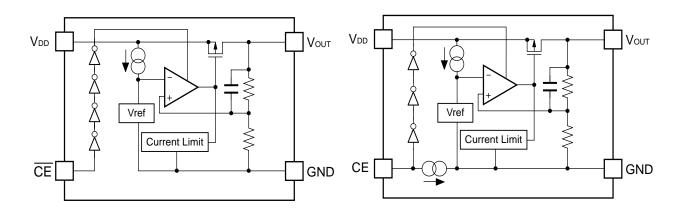
A: active low, without auto-discharge function at off state.

B: active high, without auto-discharge function at off state.

D: active high, with auto-discharge function at off state.

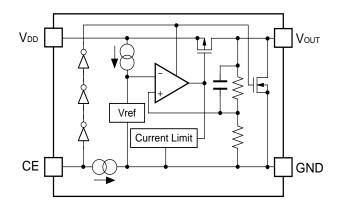
⁽¹⁾ Auto-discharge function quickly lowers the output voltage to 0 V by releasing the electrical charge in the external capacitor when the chip enable signal is switched from the active mode to the standby mode.

BLOCK DIAGRAMS



RP130xxx1A Block Diagram

RP130xxx1B Block Diagram



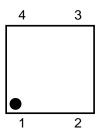
RP130xxx1D Block Diagram

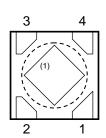
No. EA-173-180607

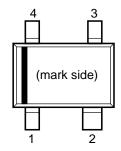
PIN DESCRIPTIONS

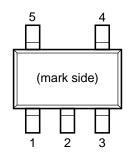
Top View

Bottom View









DFN(PLP)1010-4 Pin Configuration

SC-82AB Pin Configuration

SOT-23-5 Pin Configuration

DFN(PLP)1010-4 Pin Description

Pin No	Symbol	Pin Description
1	VOUT	Output Pin
2	GND	Ground Pin
3	CE / CE	Chip Enable Pin ("L" Active / "H" Active)
4	VDD	Input Pin

SC-82AB Pin Description

Pin No	Symbol	Pin Description
1	CE / CE	Chip Enable Pin ("L" Active / "H" Active)
2	GND	Ground Pin
3	VOUT	Output Pin
4	VDD	Input Pin

SOT-23-5 Pin Description

001 20 01 111 20001	iptioii				
Pin No	Symbol	Pin Description			
1	VDD	Input Pin			
2	GND	Ground Pin			
3	CE / CE	Chip Enable Pin ("L" Active / "H" Active)			
4	NC	No Connection			
5	VOUT	Output Pin			

⁽¹⁾ Tab is GND level (they are connected to the reverse side of this IC). The tab is better to be connected to the GND, but leaving it open is also acceptable.

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

Symbol		Item		Rating	Unit	
V_{IN}	Input Voltage			7.0	V	
V _{CE}	Input Voltage (CE	Pin)		-0.3 to 7.0	V	
Vouт	Output Voltage	Output Voltage				
Іоит	Output Current	200	mA			
		DFN(PLP)1010-4	JEDEC STD. 51-7 Test Land Pattern	800		
P_{D}	Power Dissipation ⁽¹⁾	SC-82AB	Standard Test Land Pattern	380	mW	
		SOT-23-5	SOT-23-5 JEDEC STD. 51-7 Test Land Pattern			
Tj	Junction Temperature Range			-40 to 125	°C	
Tstg	Storage Temperature Range			-55 to 125	°C	

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings are not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Item	Rating	Unit
VIN	Input Voltage	1.7 to 6.5	V
Та	Operating Temperature Range	-40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Refer to POWER DISSIPATION for detailed information.

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ELECTRICAL CHARACTERISTICS

 $V_{IN} = V_{SET} + 1 \text{ V } (V_{OUT} > 1.5 \text{ V}), \ V_{IN} = 2.5 \text{ V } (V_{OUT} \le 1.5 \text{ V}), \ I_{OUT} = 1 \text{ mA}, \ C_{IN} = C_{OUT} = 0.47 \ \mu\text{F},$ unless otherwise noted. The specifications surrounded by _____ are guaranteed by design engineering at $-40^{\circ}\text{C} \le \text{Ta} \le 85^{\circ}\text{C}$.

RP130xxx1A Electrical Characteristics

(Ta = 25°C)

	nbol Item Conditions Min. Typ. Max. Unit							
Symbol	Item	Co	onaiti	<u> </u>	Min.	Тур.	Max.	Unit
		$V_{SET} > 2.0 \text{ V}$		V _{SET} > 2.0 V	x 0.99		x 1.01	V
V_{OUT}	Output Voltage	14 - 25 0		V _{SET} ≤ 2.0 V	-20		20	mV
VOUT	Out Voltage	40°C < To < C)F0C	V _{SET} > 2.0 V	x0.985		x1.015	٧
		-40°C ≤ Ta ≤ 8	35°C	V _{SET} ≤ 2.0 V	-30		30	mV
I _{LIM}	Output Current Limit				150			mA
ΔV оит / ΔI оит	Load Regulation	1 mA ≤ I _{OUT} ≤ 1	50 m	Α		10	30	mV
			1.2	V ≤ V _{SET} < 1.5 V		0.67	1.00	
			1.5	V ≤ V _{SET} < 1.7 V		0.54	0.81	
		450	1.7	V ≤ V _{SET} < 2.0 V		0.46	0.68	\
V _{DIF} Dropout Voltage	Dropout voltage	I _{OUT} = 150 mA	2.0	V ≤ V _{SET} < 2.5 V		0.41	0.60	V
			2.5	V ≤ V _{SET} < 4.0 V		0.32	0.51	
			4.0	V ≤ V _{SET}		0.24	0.37	ı
Iss	Supply Current	Iout = 0 mA	I _{OUT} = 0 mA			38	58	μΑ
Istandby	Supply Current (Standby)	V _{CE} = V _{IN}	V _{CE} = V _{IN}			0.1	1.0	μΑ
$\Delta V_{ extsf{OUT}}$ $/\Delta V_{ extsf{IN}}$	Line Regulation	V _{SET} + 0.5 V ≤	V _{IN} ≤	6.5 V		0.02	0.10	%/V
RR	Ripple Rejection	f = 1 kHz, Ripple 0.2 Vp-p $V_{IN} = V_{SET} + 1 V$ $I_{OUT} = 30 \text{ mA (In case that } V_{OUT} \le 2.0 \text{ V}, V_{IN} = 3.0 \text{ V})$			80		dB	
VIN	Input Voltage				1.7		6.5	V
ΔV _{ουτ} /ΔΤα	Output Voltage Temperature Coefficient	-40°C ≤ Ta ≤ 85°C			±20		ppm /°C	
Isc	Short Current Limit	Vout = 0 V			40		mA	
Vсен	CE Input Voltage "H"				1.0			μΑ
VCEL	CE Input Voltage "L"						0.4	
en	Output Noise	BW = 10 Hz to lout = 30 mA	BW = 10 Hz to 100 kHz lout = 30 mA			20 xV _{SET}		μVrms

All test items listed under *Electrical Characteristics* are done under the pulse load condition ($Tj \approx Ta = 25$ °C) except for Output Noise, Ripple Rejection, and Output Voltage Temperature Coefficient.

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ELECTRICAL CHARACTERISTICS (continued)

 $V_{IN}=V_{SET}+1~V$ (Vout > 1.5 V), $V_{IN}=2.5~V$ (Vout \leq 1.5 V), $I_{OUT}=1~mA,~C_{IN}=C_{OUT}=0.47~\mu F,$ unless otherwise noted.

The specifications surrounded by are guaranteed by design engineering at -40° C \leq Ta \leq 85°C.

	x1B/D Electrical Characte					1	,	= 25°C)
Symbol	Item	Co	ndit	ions	Min.	Тур.	Max.	Unit
		Ta = 25°C		V _{SET} > 2.0 V	x 0.99		x 1.01	V
Vоит	Output Voltage	14 - 20 0		V _{SET} ≤ 2.0 V	-20		20	mV
VOUT	ou.put voitago	-40°C ≤ Ta ≤ 8	5°C	V _{SET} > 2.0 V	x 0.985		x 1.015	V
		-40 C S Ta S 0	5 C	V _{SET} ≤ 2.0 V	-30		30	mV
I _{LIM}	Output Current Limit				150			mA
Δ V ουτ /Δ I ουτ	Load Regulation	1 mA ≤ I _{OUT} ≤ 1	50 m	nA		10	30	mV
			1.2	V ≤ V _{SET} < 1.5 V		0.67	1.00	
			1.5	$V \le V_{SET} < 1.7 V$		0.54	0.81	
V_{DIF}	Dropout Voltage	I _{ОUТ} = 150 mA	1.7	V ≤ V _{SET} < 2.0 V		0.46	0.68	
V DIF	Voir Diopout Voitage	IOUT = 150 IIIA	2.0	V ≤ V _{SET} < 2.5 V		0.41	0.60	
			2.5	V ≤ V _{SET} < 4.0 V		0.32	0.51	
			4.0	V ≤ V _{SET}		0.24	0.37	
Iss	Supply Current	I _{OUT} = 0 mA	I _{OUT} = 0 mA			38	58	μΑ
Istandby	Standby Current	Vce = Vin				0.1	1.0	μΑ
ΔV _{OUT} /ΔV _{IN}	Line Regulation	V _{SET} + 0.5 V ≤ V	V _{IN} ≤	6.5 V		0.02	0.10	%/V
RR	Ripple Rejection	f = 1 kHz, Rippl V _{IN} = V _{SET} + 1 \ case that V _{OUT}	/, I _{OU}	⊤ = 30 mA (In		80		dB
V _{IN}	Input Voltage			·	1.7		6.5	V
ΔV _{Ο∪Τ} /ΔTa	Output Voltage Temperature Coefficient	-40°C ≤ Ta ≤ 8	5°C			±20		ppm /°C
Isc	Short Current Limit	Vout = 0 V	Vout = 0 V			40		mA
I _{PD}	CE Pull-down Current				0.4		μΑ	
V _{CEH}	CE Input Voltage "H"			1.0			μA	
VCEL	CE Input Voltage "L"						0.4	
en	Output Noise	BW = 10 Hz to I _{OUT} = 30 mA	BW = 10 Hz to 100 kHz lout = 30 mA			20 xV _{SET}		μVrms
RLOW	Nch ON Resistance for Auto Discharge (RP130xxx1D)	V _{IN} = 4.0 V V _{CE} = 0 V				30		Ω

All test items listed under *Electrical Characteristics* are done under the pulse load condition (Tj≈Ta=25°C) except for Output Noise, Ripple Rejection, and Output Voltage Temperature Coefficient.

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The specifications surrounded by \square are guaranteed by design engineering at -40° C \leq Ta \leq 85°C.

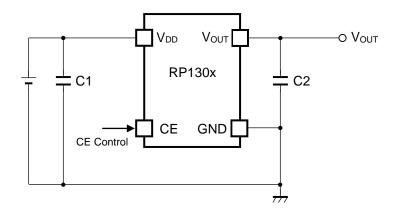
Product-specific Electrical Characteristics (Ta = 25°C)

Product Name	V _{ОUТ} [V] (Та = 25°С)			(Ta	V _{OUT} [V] = −40°C to 8	V _{DIF} [V]		
	Min.	Тур.	Max.	Min.	Тур.	Max.	Тур.	Max.
RP130x121x	1.180	1.2	1.220	1.170	1.2	1.230		
RP130x121x5	1.230	1.25	1.270	1.220	1.25	1.280	0.67	1.00
RP130x131x	1.280	1.3	1.320	1.270	1.3	1.330	0.67	1.00
RP130x141x	1.380	1.4	1.420	1.370	1.4	1.430		
RP130x151x	1.480	1.5	1.520	1.470	1.5	1.530	0.54	0.04
RP130x161x	1.580	1.6	1.620	1.570	1.6	1.630	0.54	0.81
RP130x171x	1.680	1.7	1.720	1.670	1.7	1.730		
RP130x181x	1.780	1.8	1.820	1.770	1.8	1.830	0.40	0.00
RP130x181x5	1.830	1.85	1.870	1.820	1.85	1.880	0.46	0.68
RP130x191x	1.880	1.9	1.920	1.870	1.9	1.930	1	
RP130x201x	1.980	2.0	2.020	1.970	2.0	2.030		
RP130x211x	2.079	2.1	2.121	2.069	2.1	2.132	1	
RP130x221x	2.178	2.2	2.222	2.167	2.2	2.233	0.41	0.60
RP130x231x	2.277	2.3	2.323	2.266	2.3	2.335	1	
RP130x241x	2.376	2.4	2.424	2.364	2.4	2.436	1	
RP130x251x	2.475	2.5	2.525	2.463	2.5	2.538		
RP130x261x	2.574	2.6	2.626	2.561	2.6	2.639	1	
RP130x271x	2.673	2.7	2.727	2.660	2.7	2.741	1	
RP130x281x	2.772	2.8	2.828	2.758	2.8	2.842	1	
RP130x281x5	2.822	2.85	2.879	2.807	2.85	2.893	1	
RP130x291x	2.871	2.9	2.929	2.857	2.9	2.944	1	
RP130x301x	2.970	3.0	3.030	2.955	3.0	3.045	1	
RP130x311x	3.069	3.1	3.131	3.054	3.1	3.147		
RP130x321x	3.168	3.2	3.232	3.152	3.2	3.248	0.32	0.51
RP130x331x	3.267	3.3	3.333	3.251	3.3	3.350	1	2.2.1
RP130x341x	3.366	3.4	3.434	3.349	3.4	3.451	1	
RP130x341x5	3.416	3.45	3.485	3.398	3.45	3.502	1	
RP130x351x	3.465	3.5	3.535	3.448	3.5	3.553		
RP130x361x	3.564	3.6	3.636	3.546	3.6	3.654	1	
RP130x371x	3.663	3.7	3.737	3.645	3.7	3.756		
RP130x381x	3.762	3.8	3.838	3.743	3.8	3.857		
RP130x391x	3.861	3.9	3.939	3.842	3.9	3.959		
RP130x401x	3.960	4.0	4.040	3.940	4.0	4.060		
RP130x411x	4.059	4.1	4.141	4.039	4.1	4.162		
RP130x421x	4.158	4.2	4.242	4.137	4.2	4.263		
RP130x421x5	4.208	4.25	4.293	4.186	4.25	4.314	1	
RP130x431x	4.257	4.3	4.343	4.236	4.3	4.365	1	
RP130x441x	4.356	4.4	4.444	4.334	4.4	4.466	1	
RP130x451x	4.455	4.5	4.545	4.433	4.5	4.568	1	
RP130x461x	4.554	4.6	4.646	4.531	4.6	4.669	0.24	0.37
RP130x471x	4.653	4.7	4.747	4.630	4.7	4.771	J 0.24	0.07
RP130x481x	4.752	4.8	4.848	4.728	4.8	4.872	1	
RP130x491x	4.752	4.9	4.949	4.827	4.9	4.974	1	
RP130x501x	4.851	5.0	5.050	4.925	5.0	5.075	1	
RP130x511x	5.049	5.0	5.050	5.024	5.0	5.177	1	
RP130x521x		5.1	5.252		5.1	5.278	1	
	5.148			5.122			1	
RP130x531x	5.247	5.3	5.353	5.221	5.3	5.380	<u>l</u>	

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APPLICATION INFORMATION

TYPICAL APPLICATION



RP130x Typical Application

External Components

Symbol	Descriptions
C1, C2	0.47 μF, Ceramic Capacitor, Murata, GRM155B30J474KE18B

TECHNICAL NOTES

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C2 with 0.47 μ F or more. If a tantalum capacitor is used, and its ESR (Equivalent Series Resistance) of C2 is large, the loop oscillation may result. Because of this, select C2 carefully considering its frequency characteristics.

PCB Layout

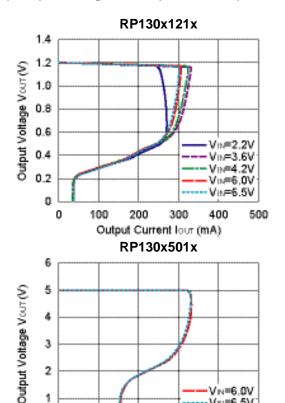
Make VDD and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C1 with a capacitance value as much as 0.47 μ F or more between VDD and GND pin, and as close as possible to the pins. Set external components, especially the output capacitor C2, as close as possible to the ICs, and make wiring as short as possible.

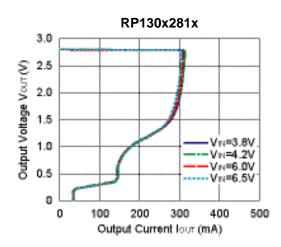
No. EA-173-180607

TYPICAL CHARACTERISTICS

Typical characteristics are intended to be used as reference data, they are not guaranteed.

1) Output Voltage vs. Output Current (C1 = 0.47 μ F, C2 = 0.47 μ F, Ta = 25°C)



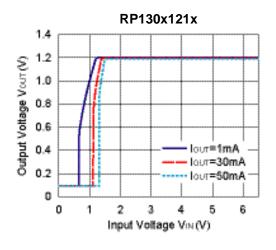


2) Output Voltage vs. Input Voltage (C1 = 0.47 μ F, C2 = 0.47 μ F, Ta = 25°C)

400

V≈=6.5V

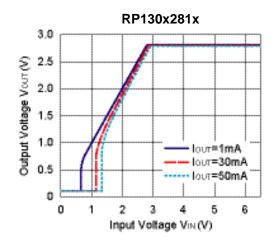
500



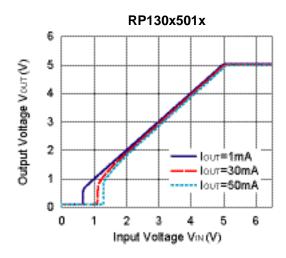
200

300

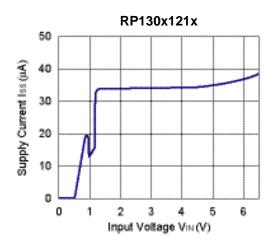
Output Current lour (mA)

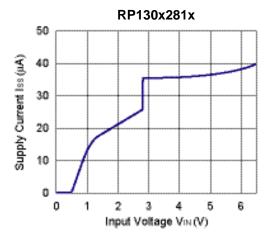


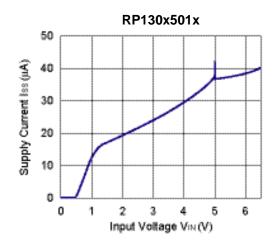
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3) Supply Current vs. Input Voltage (C1 = 0.47 μ F, C2 = 0.47 μ F, Ta = 25°C)

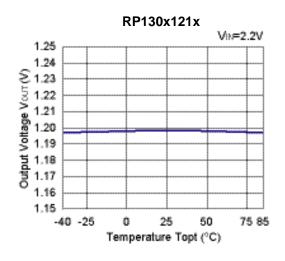


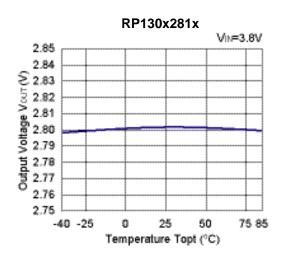


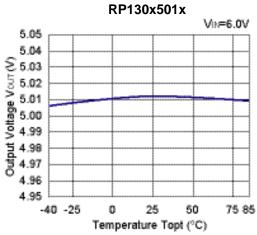


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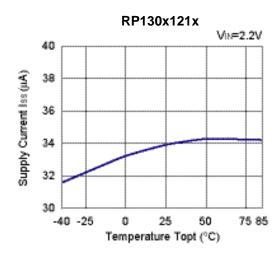
4) Output Voltage vs. Temperature (I_{OUT} = 1 mA, C1 = 0.47 μ F, C2 = 0.47 μ F)

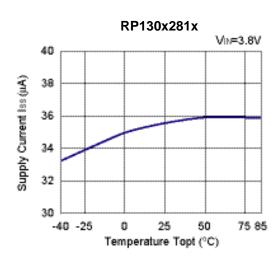


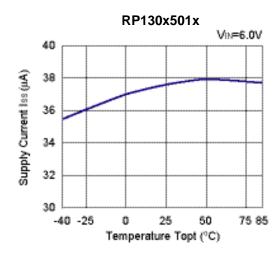




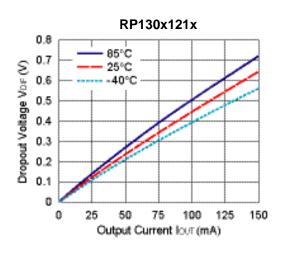
5) Supply Current vs. Temperature (IOUT = 0 mA, C1 = 0.47 μ F, C2 = 0.47 μ F)

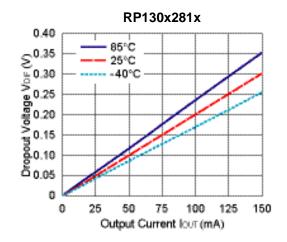


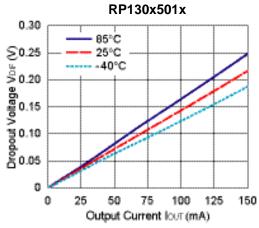




6) Dropout Voltage vs. Output Current (C1 = 0.47 μ F, C2 = 0.47 μ F)

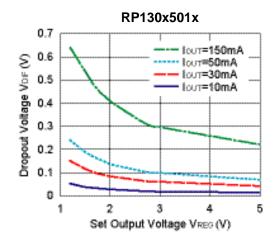




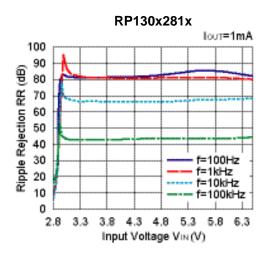


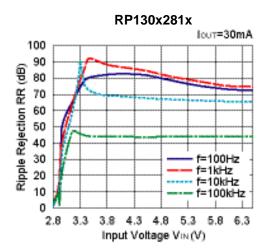
No. EA-173-180607

7) Dropout Voltage vs. Set Output Voltage (C1 = 0.47 μ F, C2 = 0.47 μ F)

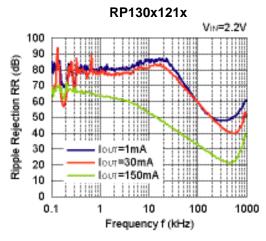


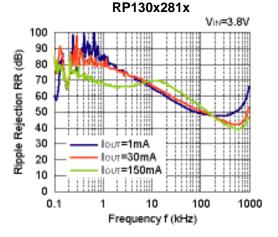
8) Ripple Rejection vs. Input Bias Voltage (C1 = none, C2 = 0.47 μ F, Ripple = 0.2 Vp-p, Ta = 25°C)

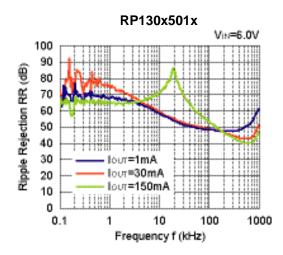




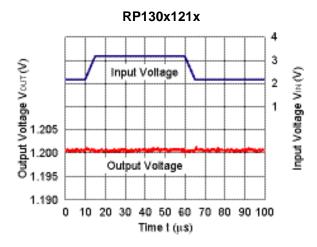
9) Ripple Rejection vs. Frequency (C1 = none, C2 = 0.47 μ F, Ripple = 0.2 Vp-p, Ta = 25°C)

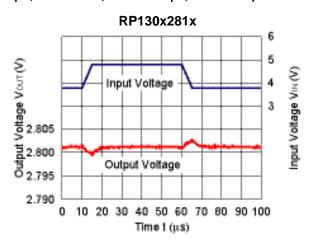


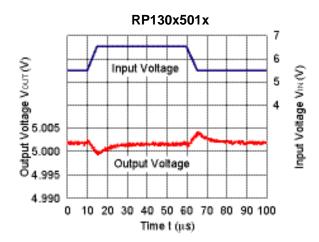




10) Input Transient Response ($I_{OUT} = 30$ mA, $tr = tf = 5 \mu s$, C1 = none, C2 = 0.47 μF , Ta = 25°C)



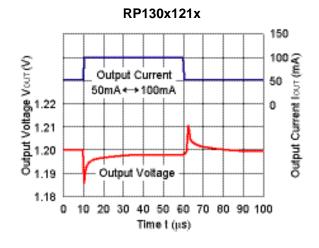


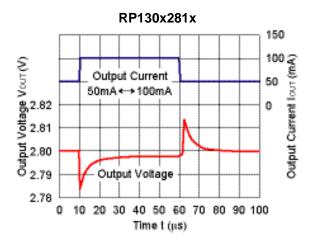


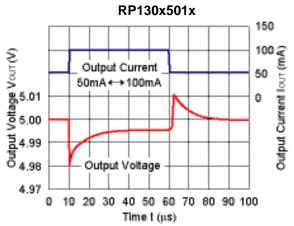
No. EA-173-180607

11) Load Transient Response

(tr = tf = 0.5 μ s, C1 = 0.47 μ F, C2 = 0.47 μ F, lout = 50mA \leftrightarrow 100 mA, Ta = 25°C)

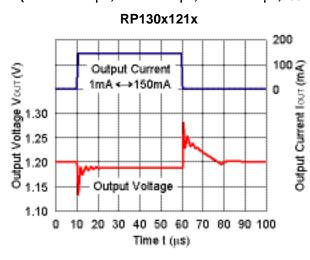


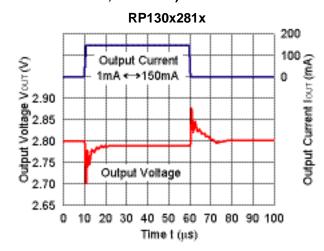




12) Load Transient Response

(tr = tf = 0.5 μ s, C1 = 0.47 μ F, C2 = 0.47 μ F, louT = 1 mA \leftrightarrow 150mA, Ta = 25°C)





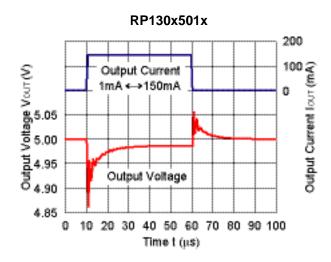
lour=30mA

3

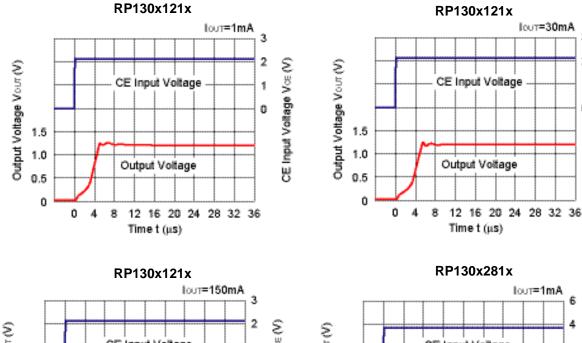
2

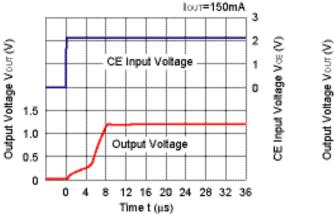
0

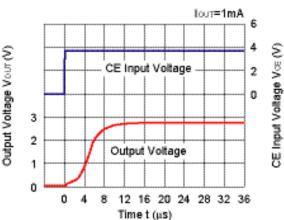
CE Input Voltage Vo∈ (V)



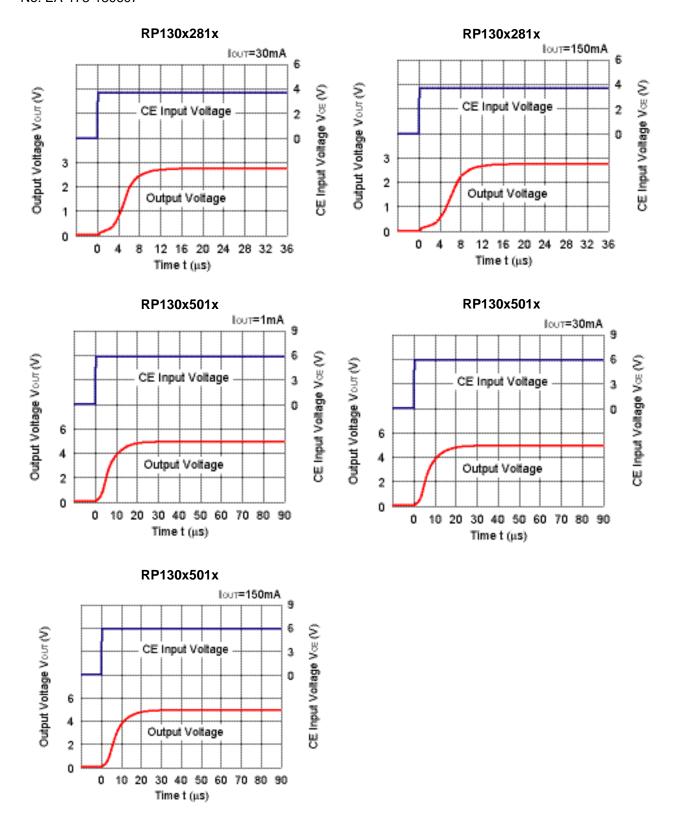
13) Turn On Speed with CE pin (C1 = 0.47 μ F, C2 = 0.47 μ F, Ta = 25°C)



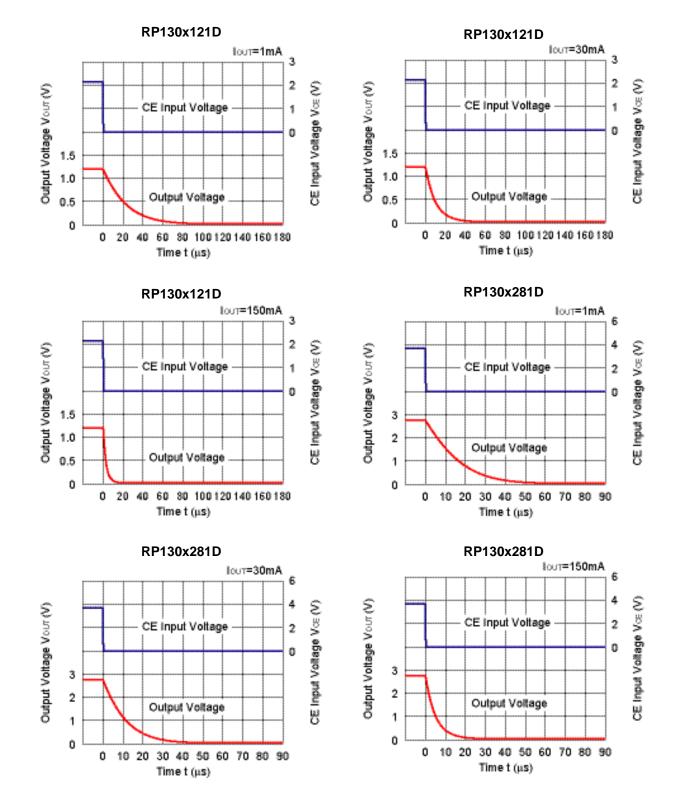




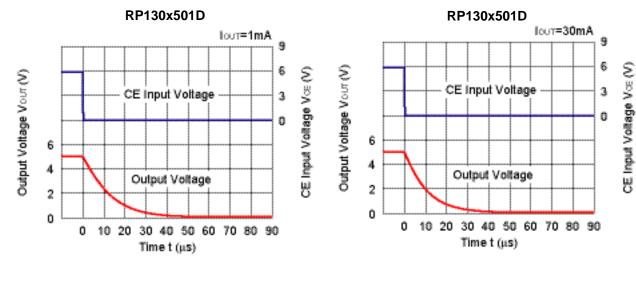
No. EA-173-180607

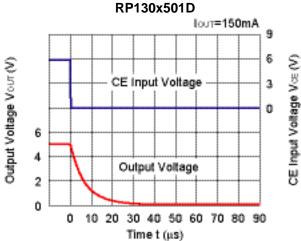


14) Turn Off Speed with CE pin (RP130xxx1D) (C1 = 0.47 μ F, C2 = 0.47 μ F, Ta = 25°C)

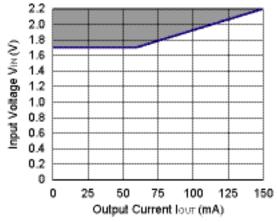


No. EA-173-180607





15) Minimum Operating Voltage (C1 = 0.47 μ F, C2 = 0.47 μ F)



Hatched area is available for 1.2 V output.

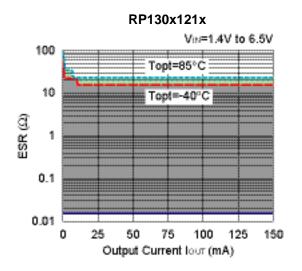
ESR vs. Output Current

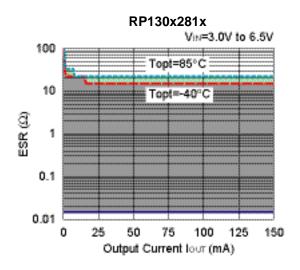
When using these ICs, consider the following points:

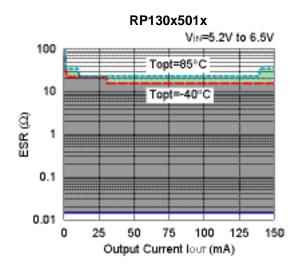
The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The conditions when the white noise level is under 40 μV (Avg.) are marked as the hatched area in the graph.

Measurement conditions

Frequency Band : 10 Hz to 3 MHz Temperature : -40° C to 85°C C1, C2 : 0.47 μ F







The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
	Outer Layer (First Layer): Less than 95% of 50 mm Square
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 11 pcs

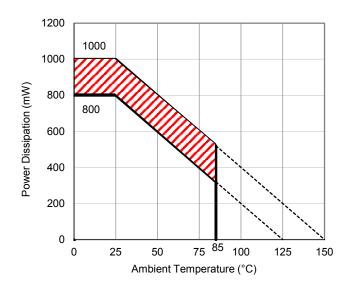
Measurement Result

 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

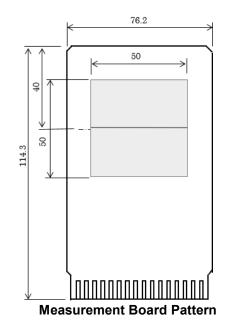
Item	Measurement Result
Power Dissipation	800 mW
Thermal Resistance (θja)	θja = 125°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 58°C/W

 θ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature

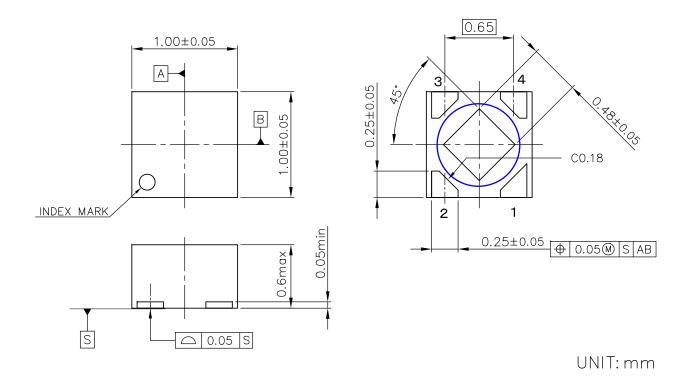


The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

RICOH

Ver. B



DFN(PLP)1010-4 Package Dimensions

* The tab on the bottom of the package shown by blue circle is a substrate potential (GND). It is recommended that this tab be connected to the ground plane on the board but it is possible to leave the tab floating.

i

Ver A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

Measurement Conditions

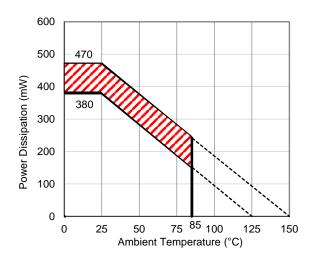
Item	Standard Land Pattern
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Double-Sided Board)
Board Dimensions	40 mm × 40 mm × 1.6 mm
Copper Ratio	Top Side: Approx. 50%
	Bottom Side: Approx. 50%
Through-holes	φ 0.5 mm × 44 pcs

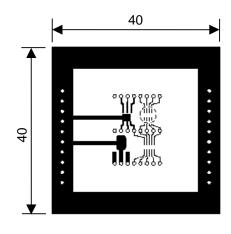
Measurement Result

 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

Item	Standard Land Pattern
Power Dissipation	380 mW
Thermal Resistance (θja)	θja = 263°C/W

θja: Junction-to-Ambient Thermal Resistance





Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

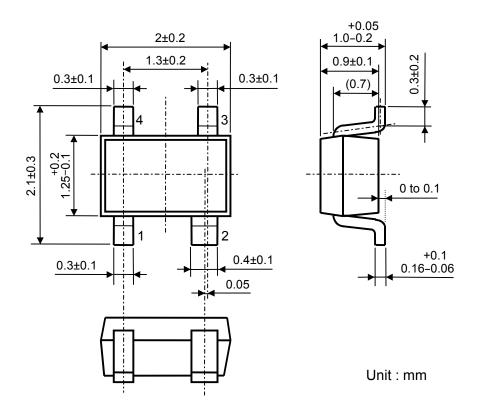
The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

RICOH

i

Ver. A



SC-82AB Package Dimensions

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 7 pcs

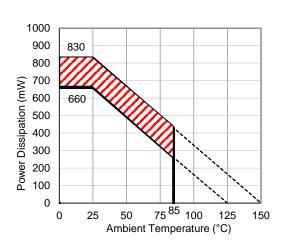
Measurement Result

 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

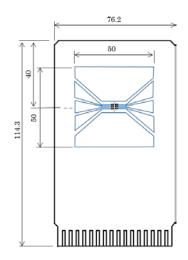
Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

 θ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



Power Dissipation vs. Ambient Temperature

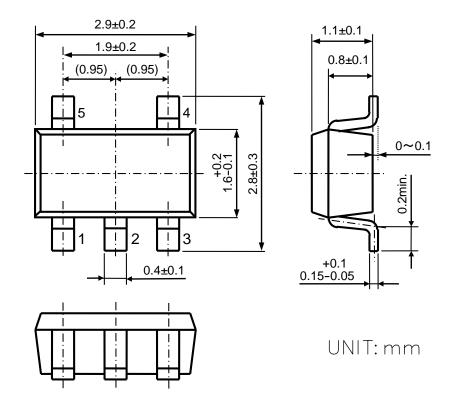


Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

Ver. A



SOT-23-5 Package Dimensions



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